

SI4423DY-T1-E3

Quote

SI4423DY-T1-E3 Information

rt Number 🖇	SI4423DY-T1-E3	
anufacturer V	Vishay Siliconix	TEL GEORGE
escription 1	MOSFET P-CH 20V 10A 8-SOIC	
ckage 8	8-SOIC (0.154", 3.90mm Width)	
		Request a
	anufacturer ategory escription ckage	Transistors - FETs, MOSFETs - SingleescriptionMOSFET P-CH 20V 10A 8-SOIC

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



SI4423DY-T1-E3 Specifications

Manufacturer Part Number	SI4423DY-T1-E3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-SOIC (0.154", 3.90mm Width)
Series	TrenchFET?
FET Type	P-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	20V
Current - Continuous Drain (Id) @ 25°C	10A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	1.8V, 4.5V
Vgs(th) (Max) @ Id	900mV @ 600µA
Gate Charge (Qg) (Max) @ Vgs	175nC @ 5V
Input Capacitance (Ciss) (Max) @ Vds	-
Vgs (Max)	$\pm 8 \mathrm{V}$
FET Feature	-
Power Dissipation (Max)	1.5W (Ta)
Rds On (Max) @ Id, Vgs	7.5 mOhm @ 14A, 4.5V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	8-SO
Package / Case	8-SOIC (0.154", 3.90mm Width)
	Report errors?

SI4423DY-T1-E3 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

SI4423DY-T1-E3 Payment Methods



SI4423DY-T1-E3 Shipping Methods



If you have any question about SI4423DY-T1-E3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com